2-input Exclusive-OR Gate

HITACHI

ADE-205-322C (Z) 4th. Edition April 2001

Description

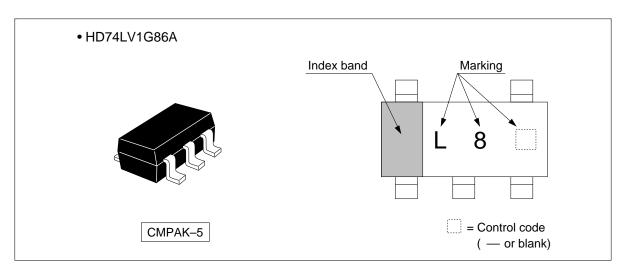
The HD74LV1G86A performs the Boolean functions $Y = A \oplus B$ or $Y = \overline{A}B + A\overline{B}$ in positive logic. A common application is as a true / complement element. If one of the inputs is low, the other input will be reproduced in true form at the output. If one of the inputs is high, the signal on the other input will be reproduced inverted form at the output. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

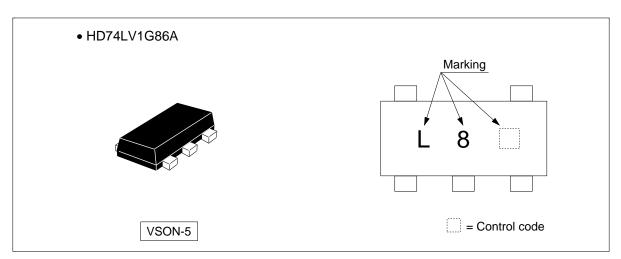
Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- Electrical characteristics equivalent to the HD74LV86A Supply voltage range: 1.65 to 5.5 V
 Operating temperature range: -40 to +85°C
- All inputs V_{IH} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Output current ± 6 mA (@V_{CC} = 3.0 V to 3.6 V), ± 12 mA (@V_{CC} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.



Outline and Article Indication



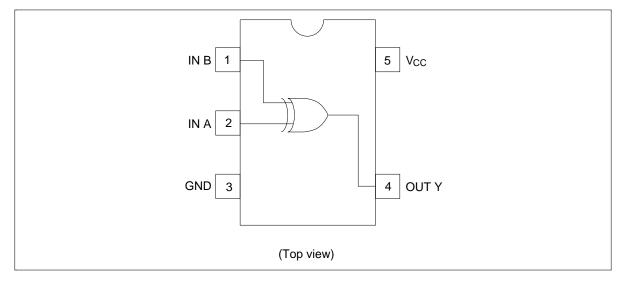


Function Table

Inputs		Output Y	
A	В		
L	L	L	
L	Н	Н	
Н	L	Н	
Н	Н	L	

H : High level L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions	
Supply voltage range	V _{cc}	–0.5 to 7.0	V		
Input voltage range *1	V _I	-0.5 to 7.0	V		
Output voltage range *1,2	V _o	-0.5 to $V_{CC} + 0.5$	V	Output : H or L	
		-0.5 to 7.0		V _{cc} : OFF	
Input clamp current	I _{IK}	-20	mA	V ₁ < 0	
Output clamp current	I _{ok}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$	
Continuous output current	Io	±25	mA	$V_{\rm O} = 0$ to $V_{\rm CC}$	
Continuous current through V _{cc} or GND	I _{CC} or I _{GND}	±50	mA		
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW		
Storage temperature	Tstg	-65 to 150	°C		

Notes:

The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150° C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	1.65	5.5	V	
Input voltage range	V _I	0	5.5	V	"
Output voltage range	Vo	0	V _{cc}	V	
Output current	I _{OL}	_	1	mA	V _{cc} = 1.65 to 1.95 V
		_	2		V_{cc} = 2.3 to 2.7 V
		_	6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	12		V_{cc} = 4.5 to 5.5 V
	I _{OH}		-1		V_{cc} = 1.65 to 1.95 V
		_	-2		V_{cc} = 2.3 to 2.7 V
		_	-6		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		_	-12		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt / Δν	0	300	ns / V	V_{cc} = 1.65 to 1.95 V
		0	200		V_{cc} = 2.3 to 2.7 V
		0	100		$V_{cc} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20		$V_{cc} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	T _a	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

• $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V _{cc} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	1.65 to 1.95	V _{cc} ×0.75	_	_	V	
		2.3 to 2.7	V _{cc} ×0.7	_		_	
		3.0 to 3.6	V _{cc} ×0.7	_	_	=	
		4.5 to 5.5	V _{cc} ×0.7	_		_	
	V _{IL}	1.65 to 1.95	_		V _{cc} ×0.25	_	
		2.3 to 2.7	_	_	V _{cc} ×0.3	_	
		3.0 to 3.6	_	_	V _{cc} ×0.3	_	
		4.5 to 5.5	_	_	V _{cc} ×0.3		
Hysteresis voltage	V_{H}	1.8	_	0.25	_	V	$V_T^+ - V_T^-$
		2.5	_	0.30	_		
		3.3	_	0.35		_	
		5.0	_	0.45			
Output voltage	V_{OH}	Min to Max	V _{cc} -0.1	_	_	V	$I_{OH} = -50 \mu A$
		1.65	1.4	_			$I_{OH} = -1 \text{ mA}$
		2.3	2.0	_	_		$I_{OH} = -2 \text{ mA}$
		3.0	2.48	_	_		$I_{OH} = -6 \text{ mA}$
		4.5	3.8	_	_		$I_{OH} = -12 \text{ mA}$
	V _{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		1.65	_	_	0.3		I _{OL} = 1 mA
		2.3	_	_	0.4	_	I _{OL} = 2 mA
		3.0	_	_	0.44		$I_{OL} = 6 \text{ mA}$
		4.5	_	_	0.55	_	I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I _{cc}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
Output leakage current	I _{OFF}	0			5	μΑ	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	C _{IN}	3.3	_	2.5	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 1.8 \pm 0.15 \text{ V}$

Item	Symbol	$T_a = 2$	25°C $T_a = -40 \text{ to } 85^{\circ}\text{C}$		Unit	Test	FROM	ТО		
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	15.8	29.4	1.0	33.0	ns	C _L = 15 pF	A or B	Υ
delay time	$t_{\tiny PHL}$	_	22.6	40.9	1.0	45.0	_	C _L = 50 pF	_	

• $V_{CC} = 2.5 \pm 0.2 \text{ V}$

Item	Symbol	$T_a = 2$	= 25°C $T_a = -40 \text{ to } 85$ °C U		Unit	Test	FROM	TO		
		Min	Тур	Max	Min	Max		Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	9.4	17.6	1.0	21.0	ns	C _L = 15 pF	A or B	Υ
delay time	$t_{\tiny PHL}$	_	12.6	22.6	1.0	26.5		C _L = 50 pF		

• $V_{CC} = 3.3 \pm 0.3 \text{ V}$

Item	Symbol	$T_a = 2$	$= 25^{\circ}C$ $T_a = -40 \text{ to } 8$		10 to 85°C	Unit	Test	FROM	то	
		Min	Тур	Max	Min	Max		Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	7.0	11.0	1.0	13.0	ns	C _L = 15 pF	A or B	Υ
delay time	$t_{\tiny PHL}$	_	9.5	14.5	1.0	16.5		C _L = 50 pF		

• $V_{CC} = 5.0 \pm 0.5 V$

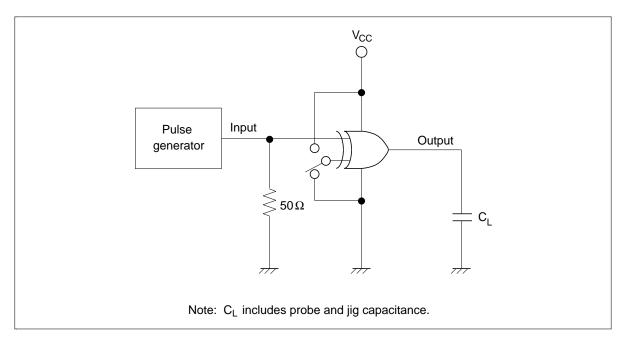
Item	Symbol	$T_a = 2$	25°C $T_a = -40 \text{ to } 85$ °C U		Unit	Test	FROM	TO		
		Min	Тур	Max	Min	Max		Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	4.8	6.8	1.0	8.0	ns	C _L = 15 pF	A or B	Υ
delay time	$t_{\tiny PHL}$	_	6.3	8.8	1.0	10.0	_	$C_L = 50 \text{ pF}$	_	

Operating Characteristics

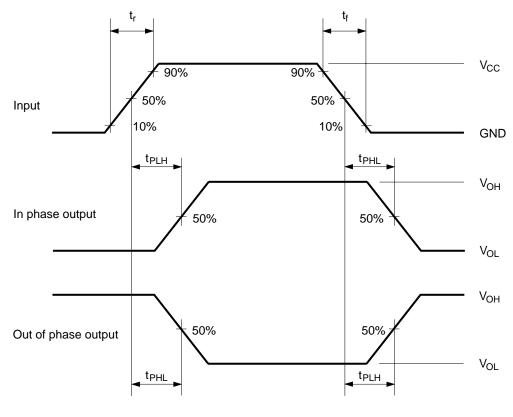
• $C_L = 50 \text{ pF}$

Item	Symbol	V _{cc} (V)	$T_a = 25$	$T_a = 25^{\circ}C$			Test Conditions	
			Min	Тур	Max			
Power dissipation capacitance	C_{PD}	3.3	_	9.5	_	pF	f = 10 MHz	
		5.0	_	11.0	_			

Test Circuit



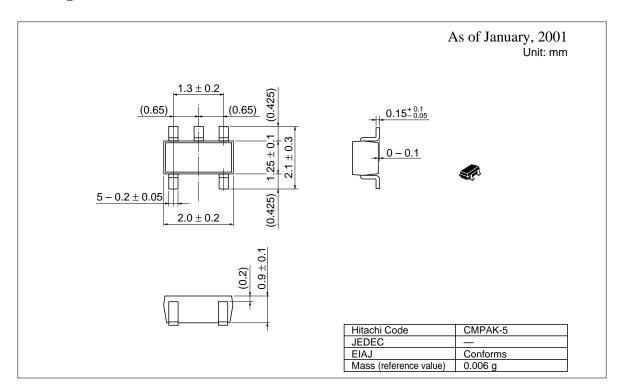
Waveforms

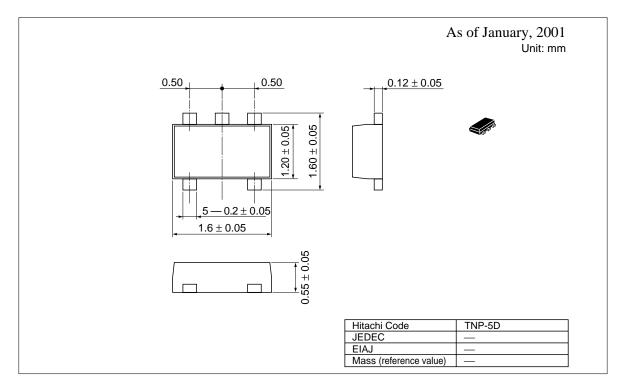


Notes: 1. Input waveform : PRR \leq 1 MHz, Zo = 50 $\Omega,\,t_f \leq$ 3 ns, $t_f \leq$ 3 ns.

2. The output are measured one at a time with one transition per measurement.

Package Dimensions





Cautions

- 1. Hitachi neither warrants nor grants licenses of any rights of Hitachi's or any third party's patent, copyright, trademark, or other intellectual property rights for information contained in this document. Hitachi bears no responsibility for problems that may arise with third party's rights, including intellectual property rights, in connection with use of the information contained in this document.
- 2. Products and product specifications may be subject to change without notice. Confirm that you have received the latest product standards or specifications before final design, purchase or use.
- 3. Hitachi makes every attempt to ensure that its products are of high quality and reliability. However, contact Hitachi's sales office before using the product in an application that demands especially high quality and reliability or where its failure or malfunction may directly threaten human life or cause risk of bodily injury, such as aerospace, aeronautics, nuclear power, combustion control, transportation, traffic, safety equipment or medical equipment for life support.
- 4. Design your application so that the product is used within the ranges guaranteed by Hitachi particularly for maximum rating, operating supply voltage range, heat radiation characteristics, installation conditions and other characteristics. Hitachi bears no responsibility for failure or damage when used beyond the guaranteed ranges. Even within the guaranteed ranges, consider normally foreseeable failure rates or failure modes in semiconductor devices and employ systemic measures such as failsafes, so that the equipment incorporating Hitachi product does not cause bodily injury, fire or other consequential damage due to operation of the Hitachi product.
- 5. This product is not designed to be radiation resistant.
- 6. No one is permitted to reproduce or duplicate, in any form, the whole or part of this document without written approval from Hitachi.
- 7. Contact Hitachi's sales office for any questions regarding this document or Hitachi semiconductor products.

HITACH

Hitachi, Ltd.

Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL NorthAmerica http://semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe http://sicapac.hitachi-asia.com Asia Japan http://www.hitachi.co.jp/Sicd/indx.htm

For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose.CA 95134

Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road

Tel: <44> (1628) 585000 Fax: <44> (1628) 585200

Hitachi Europe GmbH Electronic Components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany

Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00

Hitachi Asia Ltd. Hitachi Tower 16 Collyer Quay #20-00, Singapore 049318

URL: http://www.hitachi.com.sg Hitachi Asia Ltd.

(Taipei Branch Office) 4/F, No. 167, Tun Hwa North Road, Hung-Kuo Building,

Taipei (105), Taiwan Tel: <886>-(2)-2718-3666 Fax: <886>-(2)-2718-8180 Telex: 23222 HAS-TP

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F North Tower World Finance Centre, Harbour City, Canton Road Tsim Sha Tsui, Kowloon,

Hong Kong Tel: <852>-(2)-735-9218 Fax: <852>-(2)-730-0281

URL: http://semiconductor.hitachi.com.hk

Copyright © Hitachi, Ltd., 2001. All rights reserved. Printed in Japan. Colophon 3.0 This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.